

Figure 1: Reflection adsorption infrared spectroscopy (RAIRS) difference spectra for SiN_x surfaces with a native oxide layer after pretreatments with (a) NH_3 plasma, (b) N_2 plasma, and (c) H_2 plasma. (d) Overview of the change in surface termination groups on the SiN_x surfaces after exposure to the studied plasma pretreatments.

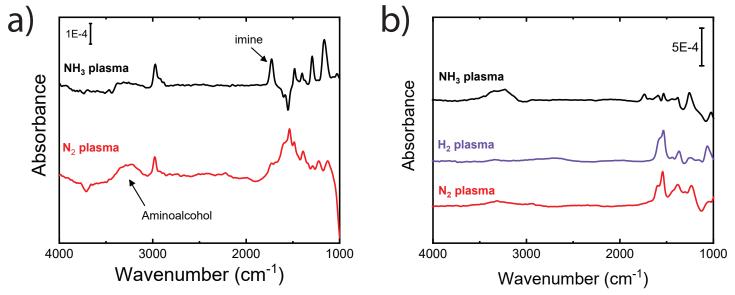


Figure 2: RAIRS spectra after (a) trimethylacetaldehyde (TMAAH) and (b) acetylacetone (Hacac) adsorption on plasma pretreated SiN_x surfaces. TMAAH was found to adsorb largely in the imine configuration after a NH_3 plasma pretreatment, while adsorbing mostly in the aminoalcohol configuration after a NL_2 plasma pretreatment. In the case of Hacac, significant adsorption was only observed on the NL_2 and NL_2 plasma pretreated SiN_x , but not on the NL_3 plasma pretreated surface.